

TECHNICAL DATA
DATA SHEET 4578, REV. –**HERMETIC POWER SCHOTTKY RECTIFIER**
Low Forward Voltage Drop

Add Suffix "S" to Part Number for S-100 Screening.

Applications:

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability

DESCRIPTION: A 200-VOLT, 30 AMP DUAL POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-4/4A/4B PACKAGE.

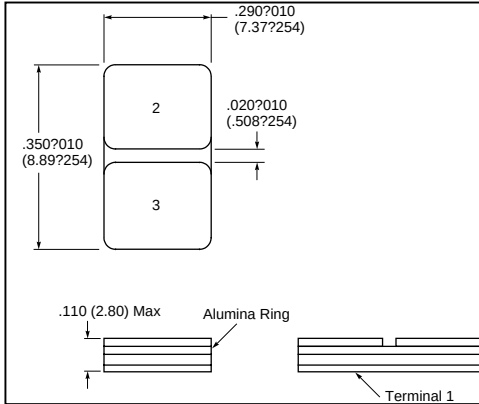
MAXIMUM RATINGSALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C = 100^\circ\text{C}$)	I_O	30	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine)	I_{FSM}	280	Amps
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.40	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	T_{op}/T_{stg}	-65 to + 200	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	T_{op}/T_{stg}	-65 to + 200	$^\circ\text{C}$

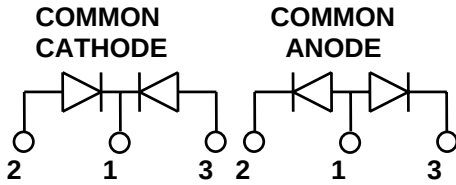
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.92 0.76	Volts
MAXIMUM REVERSE CURRENT (I_r @ 200V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.015 1.0	mA
MAXIMUM JUNCTION CAPACITANCE ($V_r = 5\text{V}$)	C_T	300	pF

Mechanical Dimensions: In Inches / mm

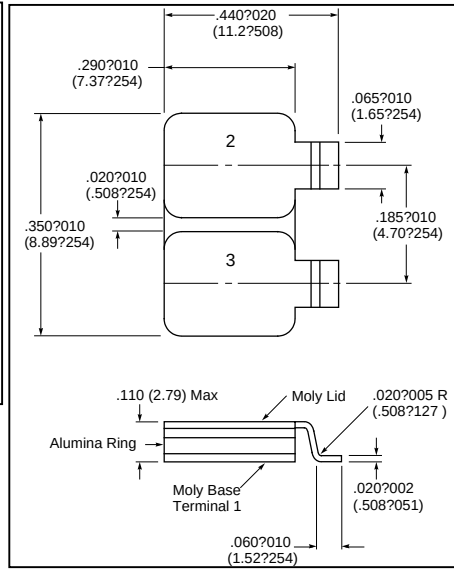


SHD-4

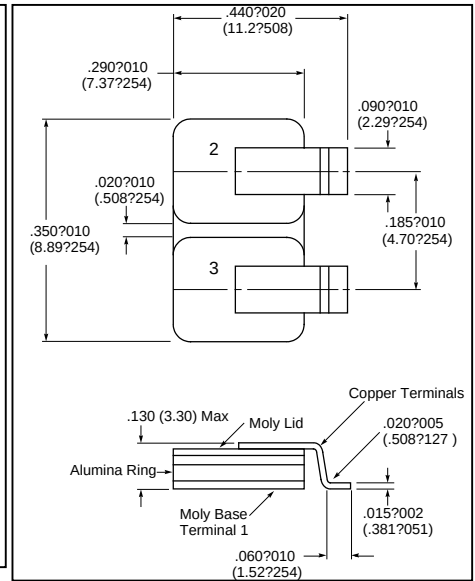


PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE (P)	COMMON CATHODE	ANODE 1	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	COMMON ANODE	CATHODE 1	CATHODE 2

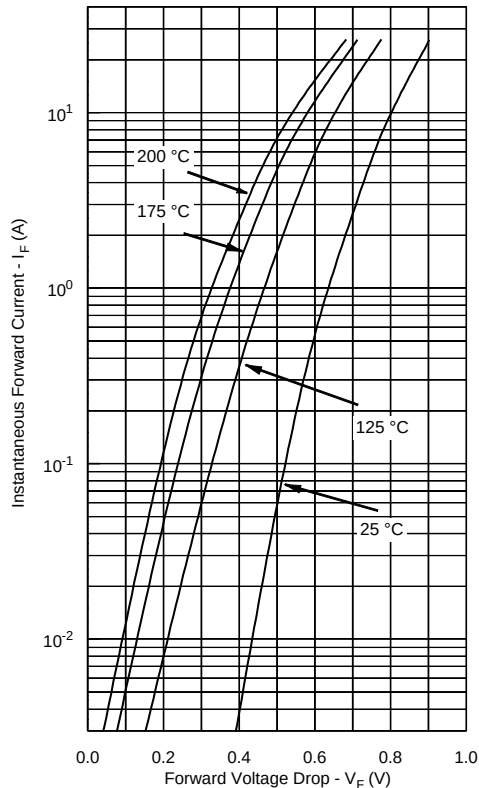


SHD-4A



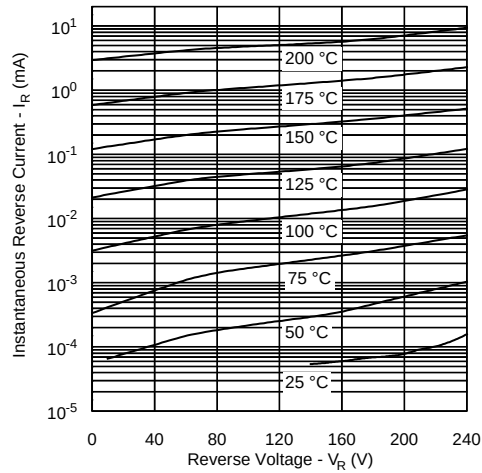
SHD-4B

Typical Forward Characteristics

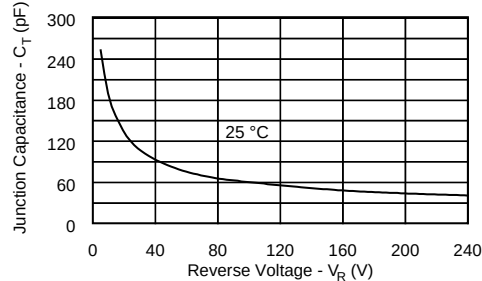


$V_F @ 1A - 55^\circ C \text{ typical} = 0.56V$

Typical Reverse Characteristics



Typical Junction Capacitance



TECHNICAL DATA

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